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LQA20T300C, LQA20B300C Qspeed[™] Family

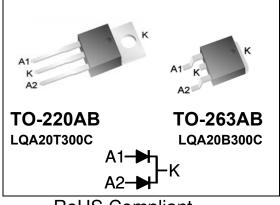


300 V, 20 A Q-Series Common-Cathode Diode

Product Summary

I _{F(AVG)} per diode	10	А
V _{RRM}	300	V
Q _{RR} (Typ at 125 °C)	38	nC
I _{RRM} (Typ at 125 °C)	2.3	А
Softness t _b /t _a (Typ at 125 °C)	0.7	

Pin Assignment



RoHS Compliant Package uses Lead-free plating and Green mold compound.Halogen free per IEC 61249-2-21.

Absolute Maximum Ratings

General Description

This device has the lowest Q_{RR} of any 300 V Silicon diode. Its recovery characteristics increase efficiency, reduce EMI and eliminate snubbers.

Applications

- AC/DC and DC/DC output rectification
 - Output & freewheeling diodes
- Motor drive circuits
- DC-AC inverters

Features

- Low Q_{RR}, Low I_{RRM}, Low t_{RR}
- High dI_F/dt capable (1000A/μs)
- Soft recovery

Benefits

- Increases efficiency
 - Eliminates need for snubber circuits
 - Reduces EMI filter component size & count
- · Enables extremely fast switching

Absolute maximum ratings are the values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Symbol	Parameter	Conditions	Rating	Units
V _{RRM}	Peak repetitive reverse voltage		300	V
I _{F(AVG)}	Average forward current	Per Diode, $T_J = 150 \text{ °C}$, $T_C = 115 \text{ °C}$	10	Α
		Per Device, $T_J = 150 \text{ °C}$, $T_C = 115 \text{ °C}$	20	Α
I _{FSM}	Non-repetitive peak surge current	60 Hz, ½ cycle	80	Α
I _{FSM}	Non-repetitive peak surge current	$\frac{1}{2}$ cycle of t = 28 µs Sinusoid, T _C = 25 °C	350	Α
TJ	Maximum junction temperature		150	°C
T _{STG}	Storage temperature		-55 to 150	°C
	Lead soldering temperature	Leads at 1.6mm from case, 10 sec	300	°C
PD	Power dissipation	$T_{\rm C} = 25 \ {\rm ^{\circ}C}$	52	W

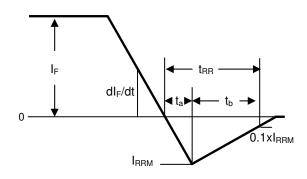
Thermal Resistance

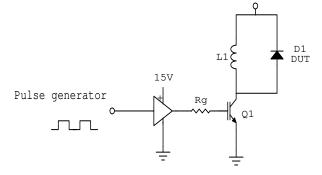
Symbol	Resistance from:	Conditions	Rating	Units
$R_{\theta JA}$	Junction to ambient	TO-220AB (only)	62	°C/W
P	Junction to case	Per Diode	2.4	°C/W
$R_{ ext{ heta}JC}$	Sufficient to case	Per Device	1.2	°C/W

Symbol	Parameter	Conditions		Min	Тур	Max	Units
DC Chara	acteristics per diode	•		•	4	•	
I _R	Reverse current per diode	V _R = 300 V, T _J = 25 °C		-	-	25	μA
		$V_{R} = 300 V, T_{J} = 1$	V _R = 300 V, T _J = 125 °C		0.32	-	mA
VF	Forward voltage per diode	$I_F = 10 \text{ A}, T_J = 25 \text{ C}$	°C	-	1.58	1.9	V
		$I_F = 10 \text{ A}, T_J = 150$	O°C	-	1.36	-	V
CJ	Junction capacitance per diode	V _R = 10 V, 1 MHz		-	33	-	pF
Dynamic	Characteristics per diod	9				•	
t _{RR} Reverse recovery time,		dl _F /dt =200 A/µs	T _J =25 °C	-	12.6	-	ns
	per diode $V_R=200, I_F=10$	V _R =200, I _F =10 A	T _J =125 °C	-	24	-	ns
Q _{RR}	Reverse recovery charge,	dl _F /dt =200 A/µs	TJ=25 °C	-	10.2	16	nC
	per diode	V _R =200, I _F =10 A	T _J =125 °C	-	38	-	nC
I _{RRM}	Maximum reverse	dl _F /dt =200 A/µs	T _J =25 °C	-	1.3	1.7	Α
	recovery current, per diode	V _R =200, I _F =10 A	T _J =125 °C	-	2.3	-	A
S		dl _F /dt =200 A/µs	T _J =25 °C	-	0.7	-	
		V _R =200, I _F =10 A T _J =125	T _J =125 °C	-	0.7	-	

Electrical Specifications at T_J= 25 °C (unless otherwise specified)

<u>Note to component engineers</u>: Q-Series diodes employ Schottky technologies in their design and construction. Therefore, component engineers should plan their test setups to be similar to traditional Schottky test setups. (For further details, see application note AN-300.)





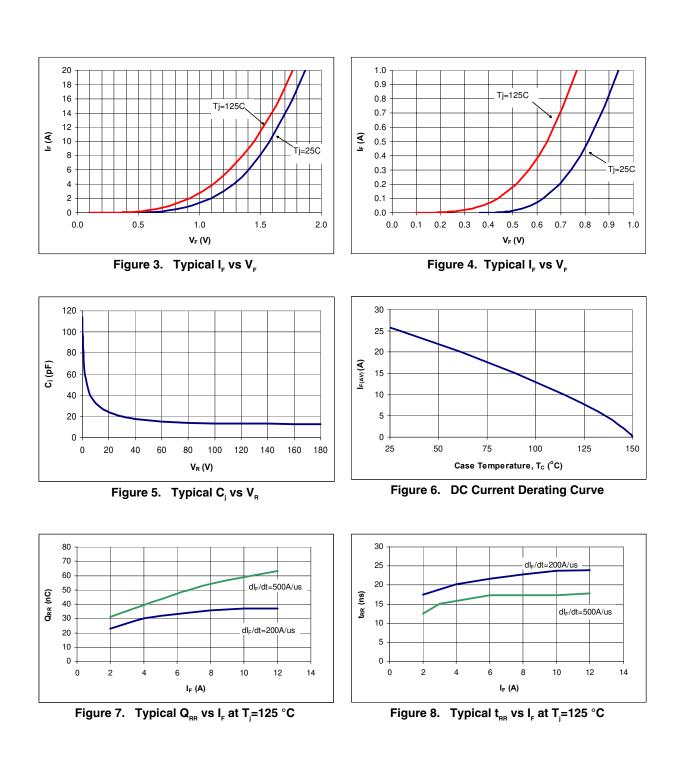
VR

Figure 1. Reverse Recovery Definitions









Electrical Specifications at T_J= 25 °C (unless otherwise specified)



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POWER NTEGRATION

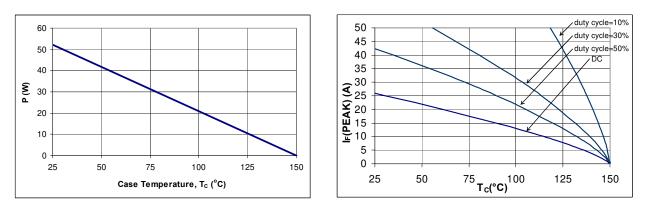


Figure 9. Power Derating Curve

Figure 10. IF(Peak) vs TC, f=70 kHz

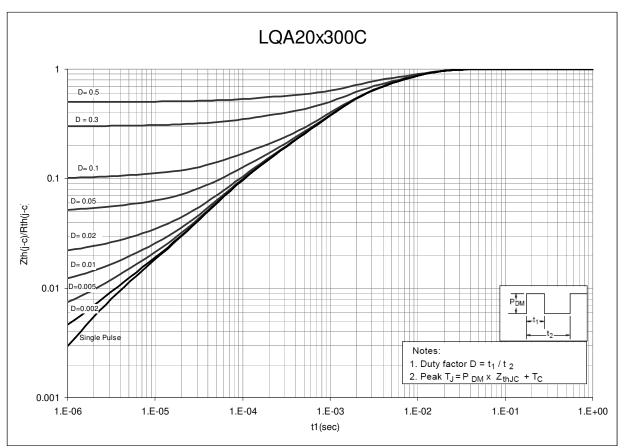


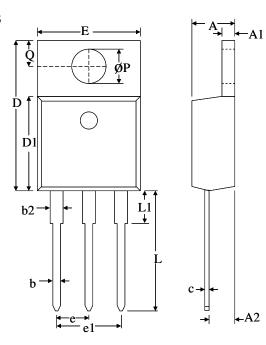
Figure 11. Normalized Maximum Transient Thermal Impedance





Dimensional Outline Drawings

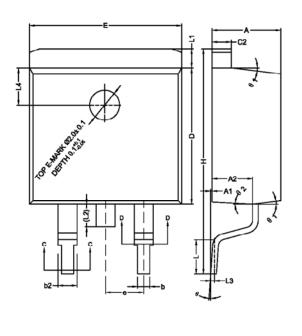
TO-220AB



	Millimeters					
Dim	MIN	MIN MAX				
Α	4.32	4.70				
A1	1.11	1.38				
A2	2.59	2.79				
b	0.77	1.00				
b2	1.23	1.36				
С	0.34	0.47				
D	14.71	15.75				
D1	9.05	9.25				
Е	9.96	10.36				
е	2.44	2.64				
e1	4.98	5.18				
L	12.70	14.22				
L1	-	3.90				
ØP	3.71	3.96				
Q	2.54	2.90				

Mechanical Mounting Method	Maximum Torque / Pressure specification
Screw through hole in package tab	1 Newton Meter (nm) or 8.8 inch-pounds (lb-in)
Clamp against package body	12.3 kilogram-force per square centimeter (kgf/cm ²) or 175 lbf/in ²

TO-263AB



	Millimeters			
Dim	MIN	МАХ		
Α	4.40	4.70		
A1	0.00	0.25		
A2	2.59	2.79		
b	0.77	0.90		
b2	1.23	1.36		
c2	1.22	1.32		
D	9.05	9.25		
E	10.06	10.26		
е	2.54 BSC	2.54 BSC		
н	14.70	15.50		
L	2.00	2.60		
L1	1.17	1.40		
L2	-	1.75		
L3	0.25 BSC	0.25 BSC		
L4	2.00 BSC	2.00 BSC		
Θ	0°	8°		
Θ1	5°	9°		
Θ2	1°	5°		





Soldering time and temperature: This product has been designed for use with high-temperature, lead-free solder. The component leads can be subjected to a maximum temperature of 300 °C, for up to 10 seconds. See Application Note AN-303, for more details.

Ordering Information

Part Number	Package	Packing
LQA20T300C	TO-220AB	50 units/tube
LQA20B300C	TO-263AB	800 units/reel

The information contained in this document is subject to change without notice.



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Revision	Notes	Date
1.4	Released by Qspeed	06/10
1.5	Converted to Power Integrations Document	01/11





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